



Rectifier Diode

Types W0735R/SA120 to W0735R/SA150

Previous Type No.: SW02-15PHN/R470

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V _{RRM}	Repetitive peak reverse voltage, (note 1)	1200-1500	V
V _{RSM}	Non-repetitive peak reverse voltage, (note 1)	1300-1600	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
I _{F(AV)M}	Maximum average forward current, T _{case} =55°C, (note 2)	735	A
I _{F(AV)M}	Maximum average forward current. T _{case} =100°C, (note 2)	551	A
I _{F(RMS)M}	Nominal RMS forward current, T _{case} =25°C, (note 2)	1325	A
I _{F(d.c.)}	D.C. forward current, T _{case} =25°C, (note 3)	1091	A
I _{FSM}	Peak non-repetitive surge t _p =10ms, V _{rm} =60%V _{RRM} , (note 3)	9000	A
I _{FSM2}	Peak non-repetitive surge t _p =10ms, V _{rm} ≤10V, (note 3)	10000	A
I ² t	I ² t capacity for fusing t _p =10ms, V _{rm} =60%V _{RRM} , (note 3)	405×10 ³	A ² s
I ² t	I ² t capacity for fusing t _p =10ms, V _{rm} ≤10V, (note 3)	500×10 ³	A ² s
T _{j op}	Operating temperature range	-40 to +190	°C
T _{stg}	Storage temperature range	-55 to +190	°C

Notes:-

- 1) De-rating factor of 0.13% per °C is applicable for T_j below 25°C.
- 2) Single phase; 50Hz, 180° half-sinewave.
- 3) Half-sinewave, 190°C T_j initial.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V _{FM}	Maximum peak forward voltage	-	-	1.3	I _{FM} =1500A	V
V _{T0}	Threshold voltage	-	-	0.79		V
r _T	Slope resistance	-	-	0.342		mΩ
I _{R_{RRM}}	Peak reverse current	-	-	15	Rated V _{R_{RRM}}	mA
R _{thJC}	Thermal resistance, junction to case	-	-	0.13		K/W
F	Mounting Torque	25.0	-	27.7		Nm
W _t	Weight		250			g

Notes:-

- 1) Unless otherwise indicated T_j=190°C.

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V_{RRM} V	V_{RSM} V	V_R DC V
12	1200	1300	800
15	1500	1600	1000

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T} \quad \text{and:} \quad W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j \max} - T_K$$

Where $V_{T0}=0.79V$, $r_T=0.342m\Omega$,

R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave	0.174	0.153	0.143	0.130
Sine wave	0.172	0.153	0.149	

Form Factors				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave	2.449	1.732	1.414	1
Sine wave	2.778	1.879	1.57	

5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F , on page 6 is represented in two ways;

- (i) the well established V_{T0} and r_T tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

25°C Coefficients		190°C Coefficients	
A	0.933861601	A	0.717850746
B	-0.019809464	B	-0.011382077
C	$0.23523937 \times 10^{-3}$	C	$0.28340238 \times 10^{-3}$
D	$5.52084713 \times 10^{-3}$	D	$6.10133431 \times 10^{-3}$

Curves

Figure 1 – Mean forward current vs. power dissipation

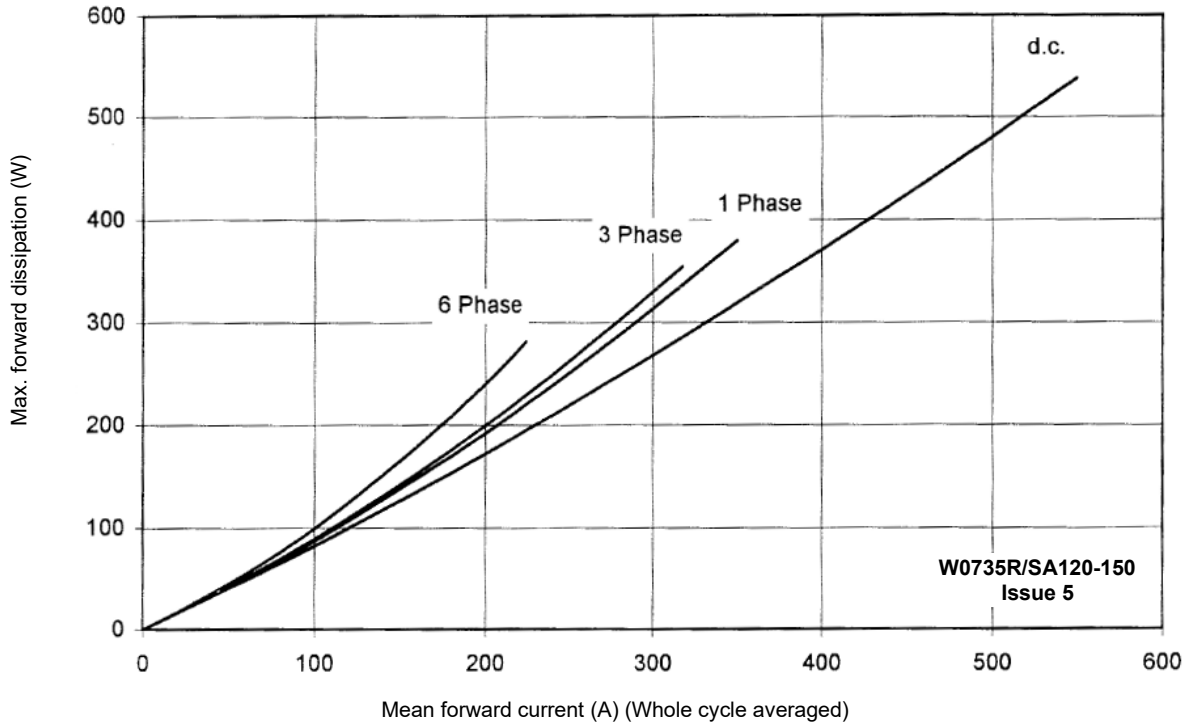


Figure 2 – Max. stud temperature vs. mean forward current

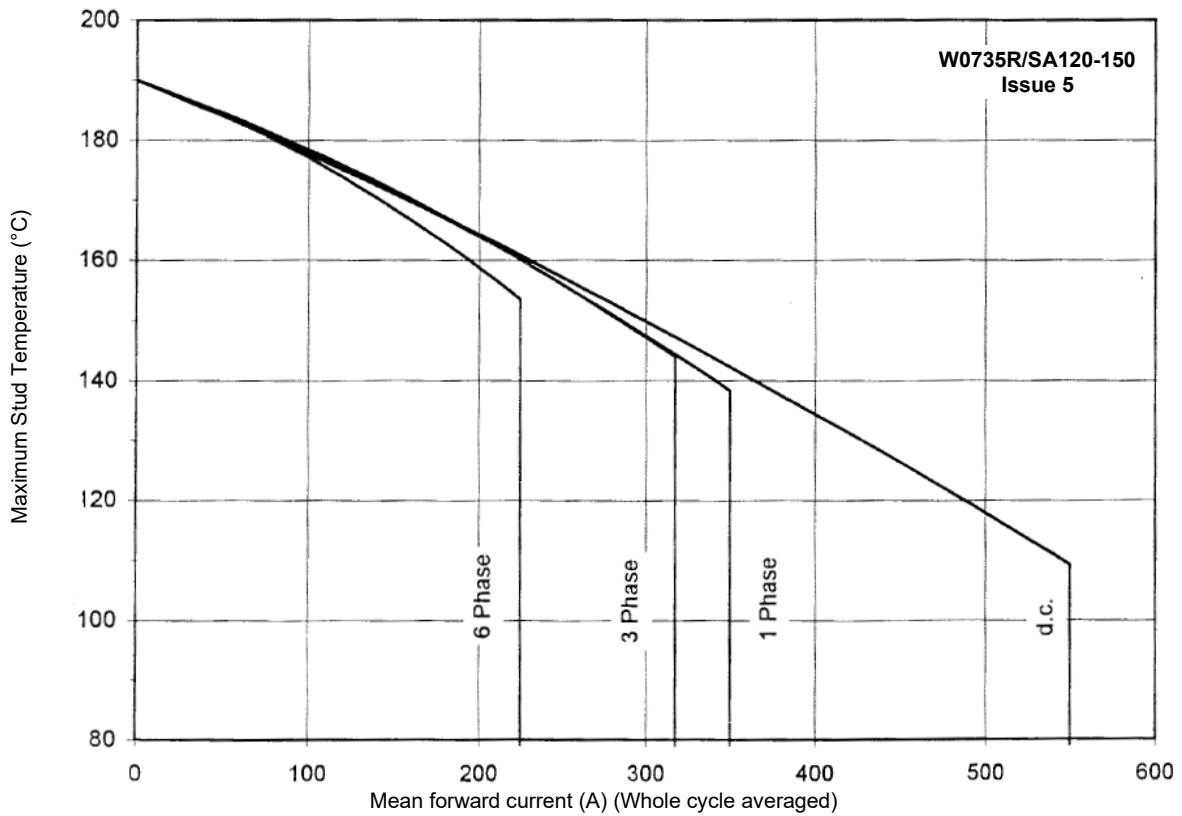


Figure 3 – Forward characteristics of limit device

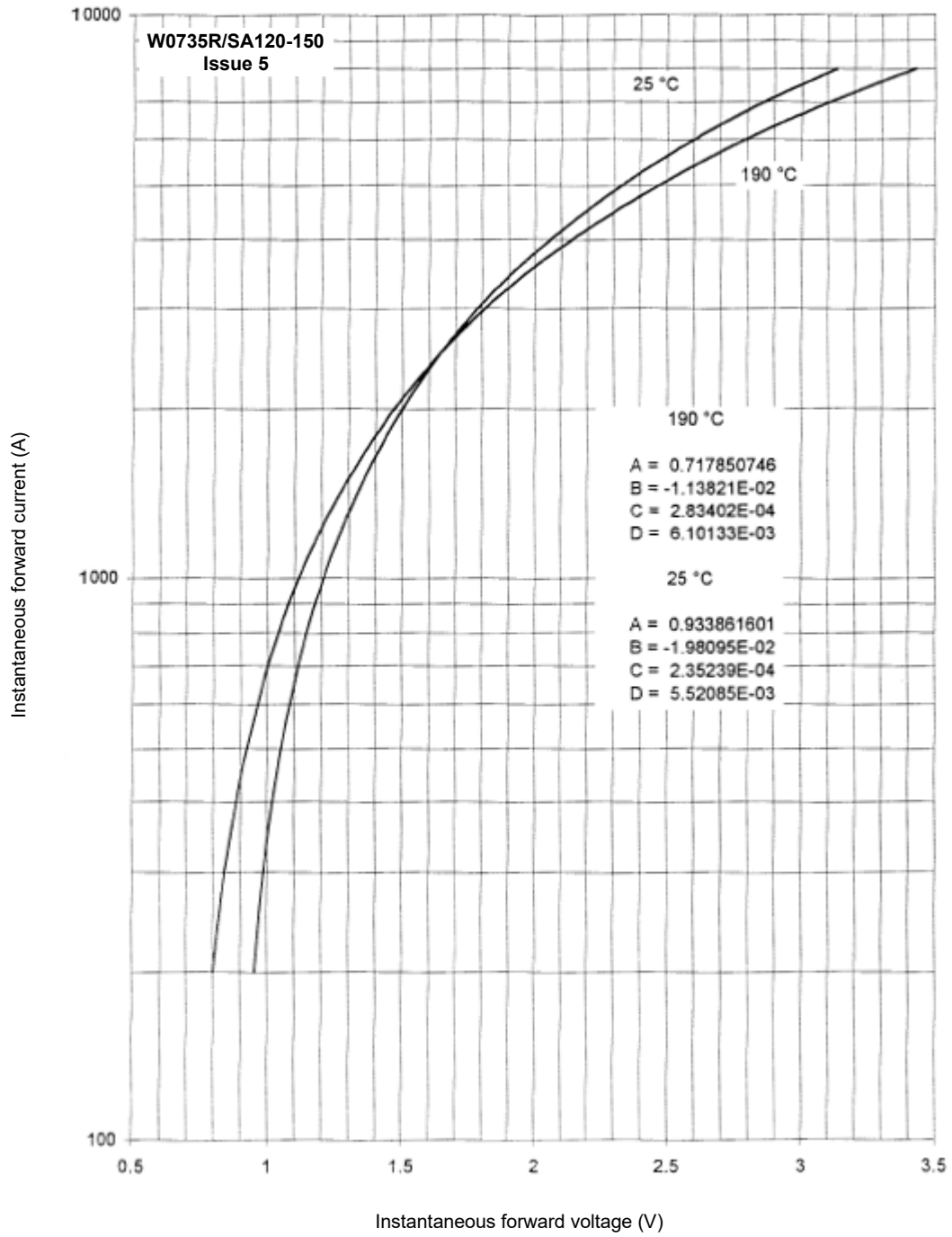


Figure 4 – Transient thermal impedance

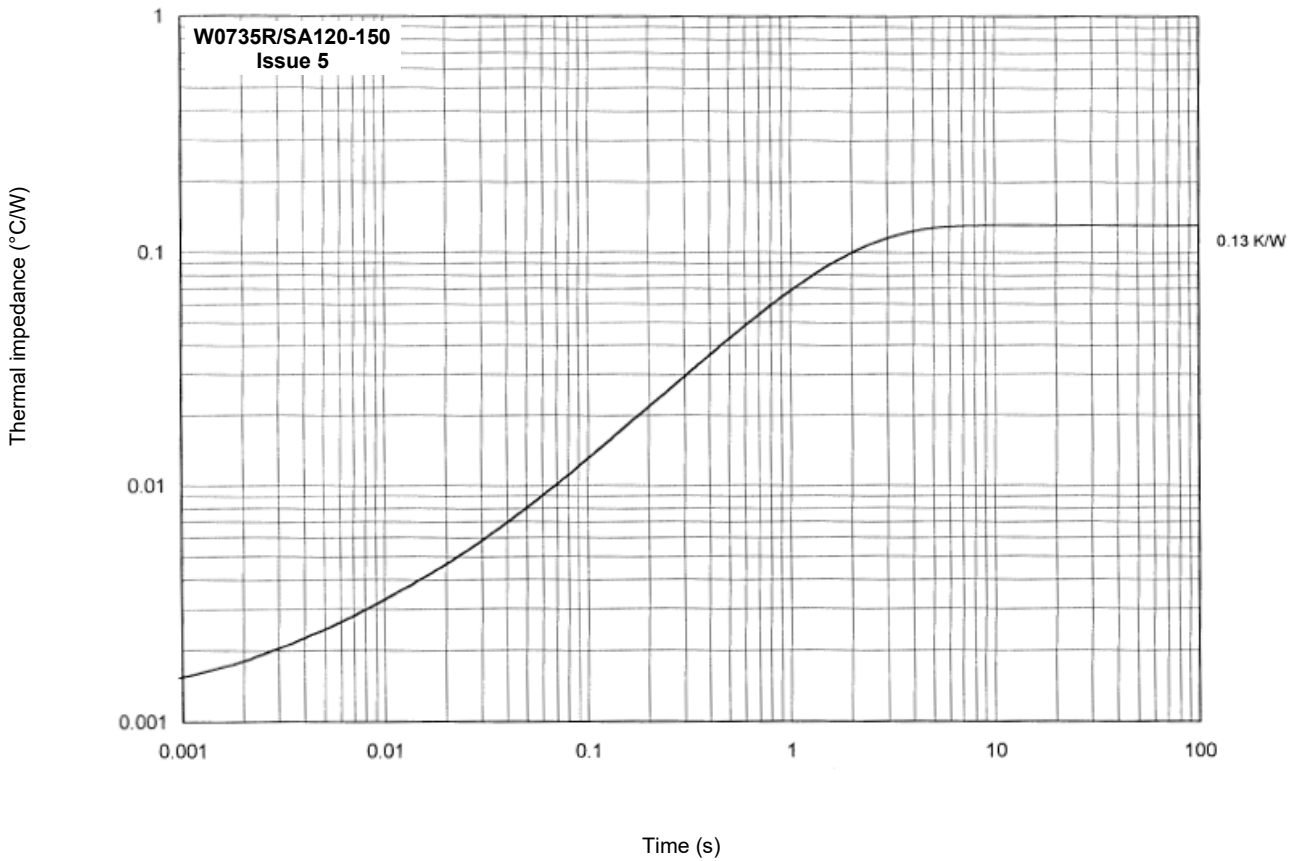
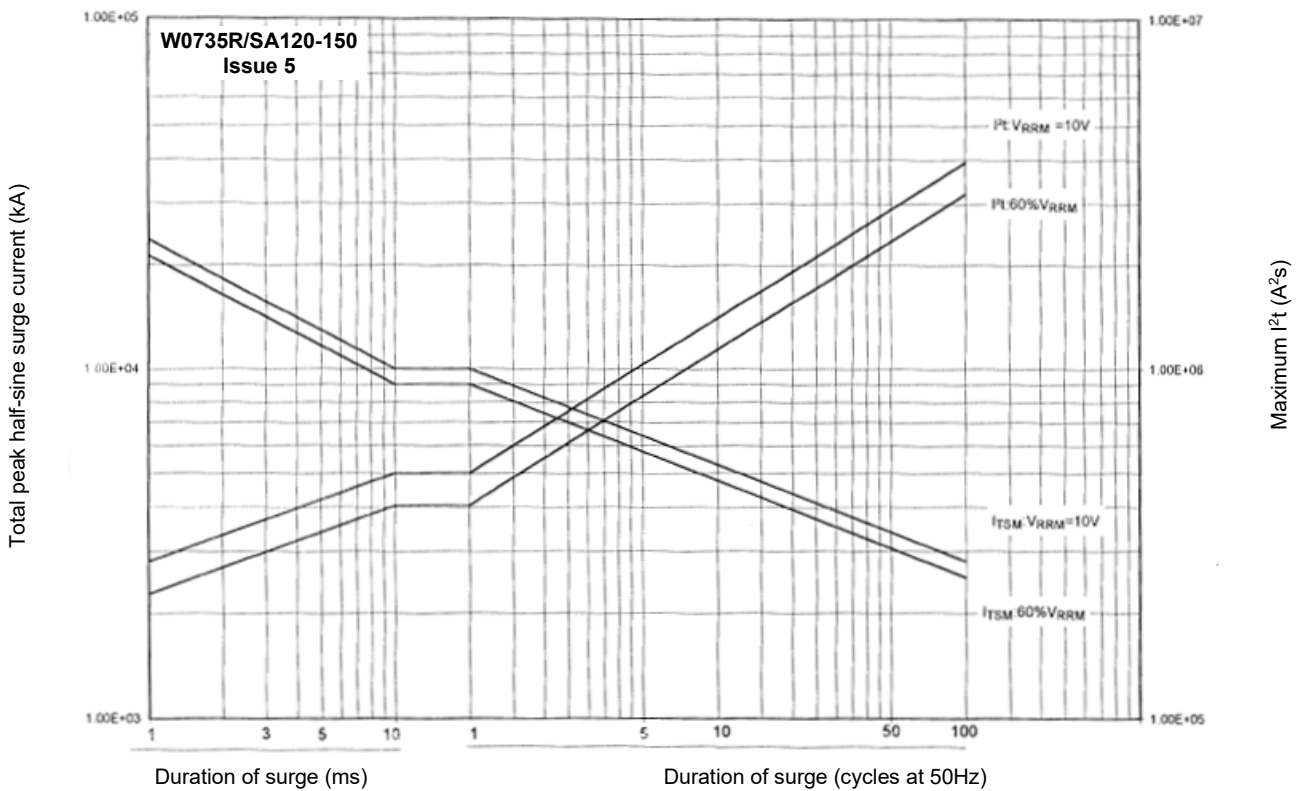
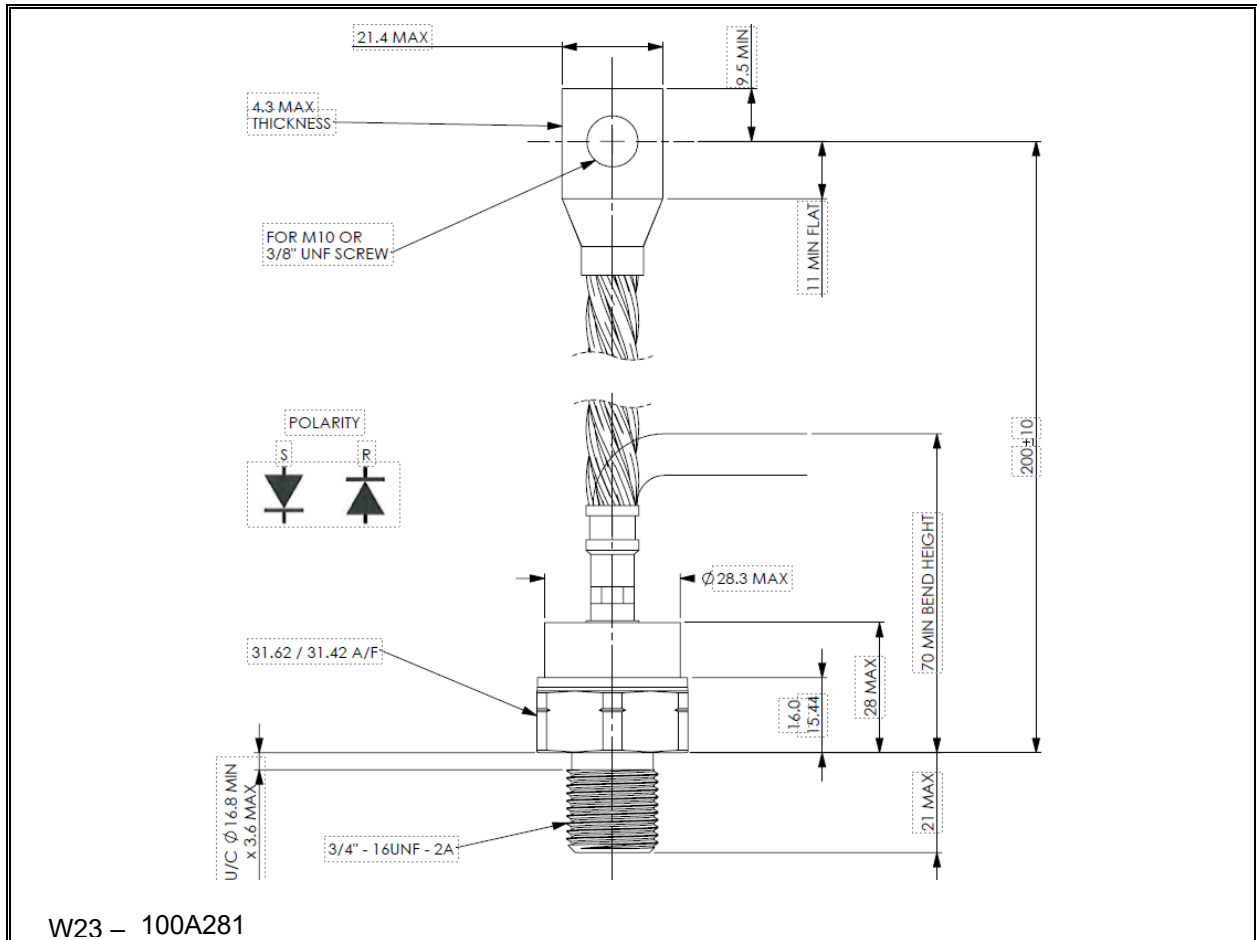


Figure 5 – Maximum non-repetitive surge current at initial junction temperature 190°C



Outline Drawing & Ordering Information

ORDERING INFORMATION

(Please quote 10 digit code as below)

W0735	#	A	◆◆	0
Fixed Type Code	Polarity code R = Base Anode S = Base Cathode	Outline code	Voltage code $V_{DRM}/100$ 12-15	Fixed code

 Order code: W0735SA150 – 1500V V_{RRM} , 3/4" stud, cathode base, high voltage metal stud housing

 IXYS UK Westcode Ltd
 Langley Park Way,
 Langley Park,
 Chippenham,
 Wiltshire, SN15 1GE.
 Tel: +44 (0)1249 444524
 E-mail:

<https://www.littelfuse.com/contactus.aspx>

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